



BRIGHTTEK
BRIGHTTEK (EUROPE) LIMITED

Brighten up The World With LED!



ISO/TS 16949:2009



BS EN ISO 14001:2004



QC 080000 IECQ HSPM

PRODUCT DATASHEET



- ▶ EMC SMD Top View
- ▶ 3838 2.15t Series
- ▶ Infrared (IR) 850nm

NOF66S96BF (Off-Axis Dom)



Release Date: 04 September 2024 Version: A1.0



3838 2.15t Series



FEATURES:

- **Package:** Black Ceramic Dual Junction with Asymmetric Lens
- **Forward Current:** 1000mA
- **Pulse Forward Current (max.):** 3
- **Forward Voltage (typ.):** 3.2V
- **Radiant Power (typ.):** 1400mW@1A
- **Radiant Intensity (typ.):** 320mW/sr@1A
- **Colour:** Infrared (IR)
- **Peak Wavelength (typ.):** 850nm
- **Viewing Angle:** X:135° / Y:35°; Off-Axis Angle Y:55°
- **Operating Temperature:** -40~+105°C
- **Storage Temperature:** -40~+105°C
- **Grouping Parameters:**
 - Forward Voltage
 - Radiant Power
 - Peak Wavelength
- **Soldering Methods:** Reflow Soldering
- **MSL Level:** MSL2 according to J-STD020
- **Corrosion Robustness Class:** 3B
- **Packing:** 12mm tape with max.800/reel, \varnothing 178mm (7")

APPLICATIONS:

- Automotive
- Security Camera
- Motion Detection
- Night Viewer
- Surveillance
- Data Communication
- Gesture Recognition
- Facial Recognition

CHARACTERISTICS:

Absolute Maximum Characteristics (T_a=25°C)

Parameter	Symbol	Ratings	Unit
DC Forward Current	I _F	1000	mA
Pulse Forward Current	I _{FP}	3	A
Power Consumption	P _{tot}	3.6	W
Reverse Voltage	V _R	5	V
Reverse Current @5V	I _R	10	μA
Junction Temperature	T _j	145	°C
Thermal Resistance Junction to Solder Point	R _{th}	typ. 6.5; max. 11	K/W
Electrostatic Discharge (HBM: MIL-STD-883 C 2)	ESD	2	kV
Operating Temperature	T _{OPR}	-40~+105	°C
Storage Temperature	T _{STG}	-40~+105	°C
Soldering Temperature	T _{SOL}	260	°C

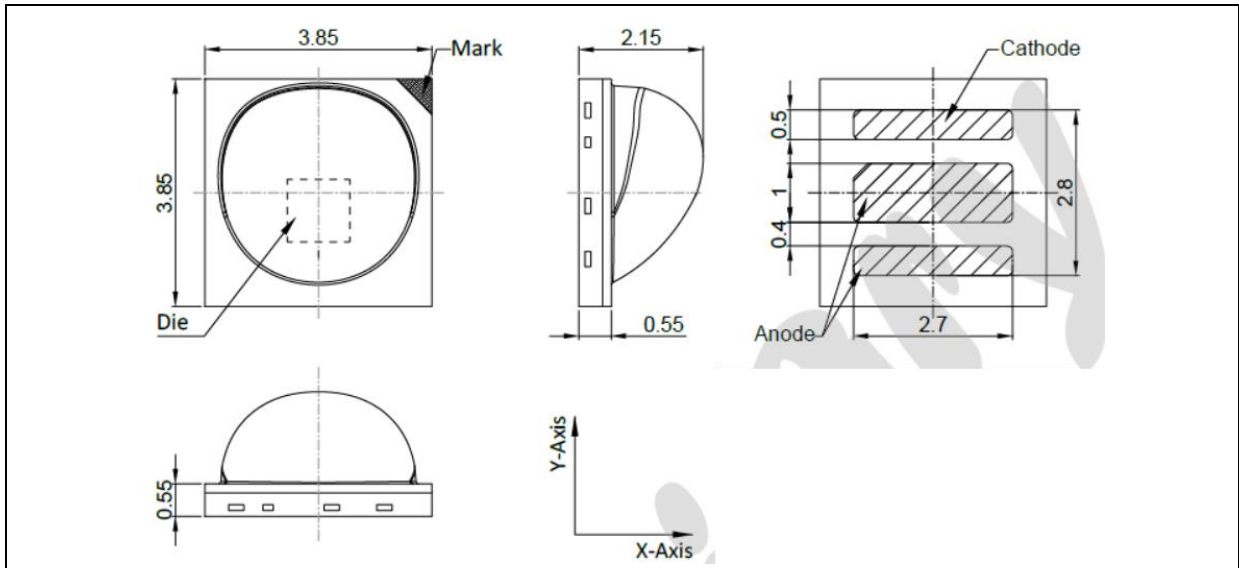
Electrical & Optical Characteristics ($T_a=25^{\circ}\text{C}$, $I_f=1\text{A}$, $t_p=10\text{ms}$)

Parameter	Symbol	Values			Unit	Test Condition	
		Min.	Typ.	Max.			
Forward Voltage	V_F	2.8	3.2	3.6	V	$I_f=1\text{A}$ $t_p=100\mu\text{s}$	
Radiant Power	Φ_e	1200	1400	1600	mW	$I_f=1\text{A}$ $t_p=100\mu\text{s}$	
Radiant Intensity	I_e	240	320	400	mW/sr	$I_f=1\text{A}$ $t_p=100\mu\text{s}$	
Peak Wavelength	λ_p	---	850	---	nm	$I_f=1\text{A}$	
Spectral Bandwidth	$\Delta\lambda$	---	35	---	nm	$I_f=1\text{A}$	
Viewing Angle	X	$2\theta_{1/2}$	---	135	---	deg	$I_f=1\text{A}$
	Y		---	35	---		
Off-Axis Angle	Y	---	---	55	---	deg	$I_f=1\text{A}$

 1. Radiant Power (P_o) $\pm 10\%$, Forward Voltage (V_f) $\pm 0.1\text{V}$, Viewing angle($2\theta_{1/2}$) $\pm 10^{\circ}$

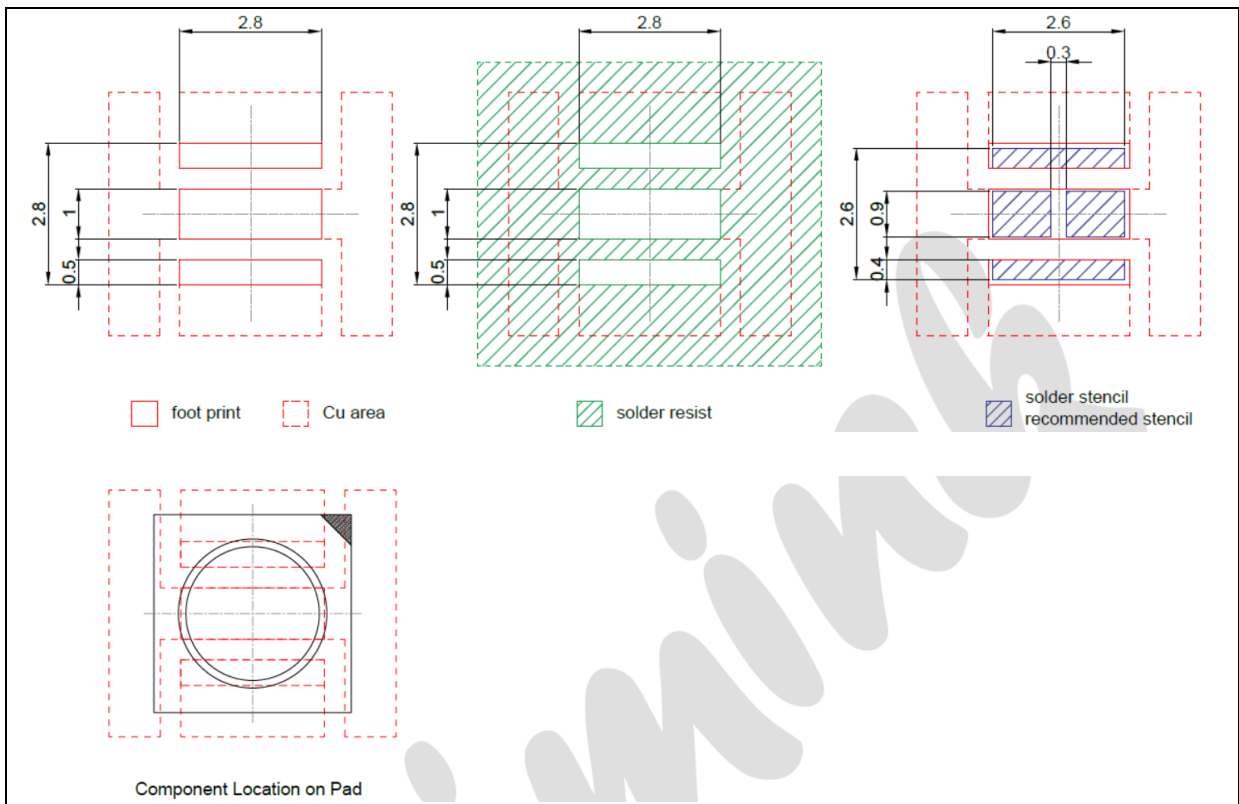
OUTLINE DIMENSION:

Package Dimension:



1. All dimensions are in millimetre (mm).
2. Tolerance $\pm 0.13\text{mm}$, unless otherwise noted.

Recommended Soldering Pad Dimension:



1. Dimensions are in millimetre (mm).
2. Tolerance $\pm 0.1\text{mm}$ with angle tolerance $\pm 0.5^\circ$.

BINNING GROUPS:

 Forward Voltage Classifications ($I_F=1A$; $t_p=10ms$):

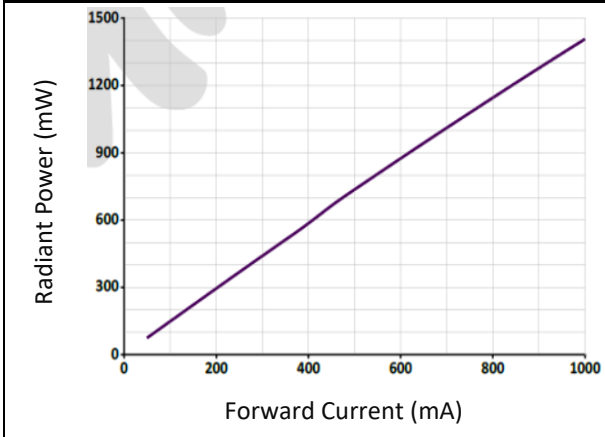
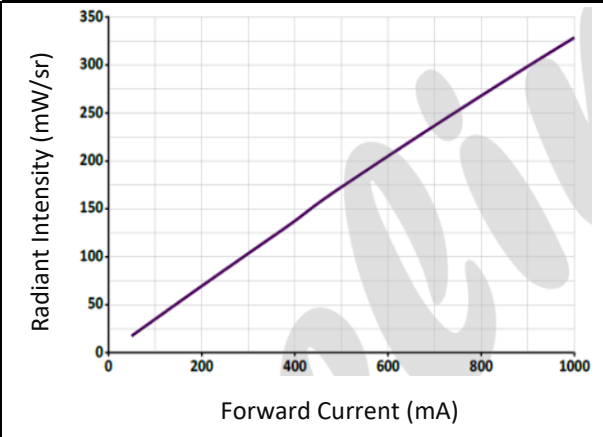
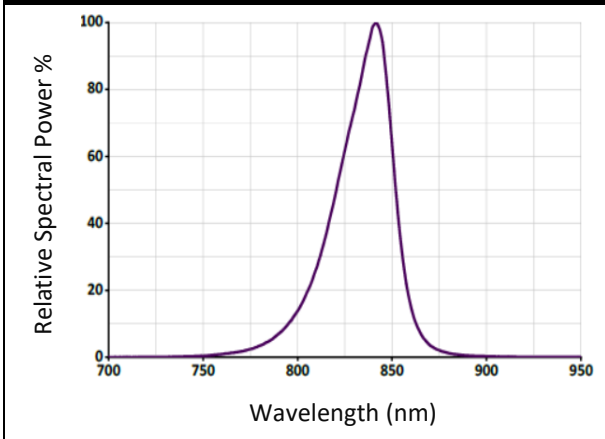
Code	Min.	Max.	Unit
KN	2.8	3.6	V

 Radiant Power Classifications ($I_F=1A$; $t_p=10ms$):

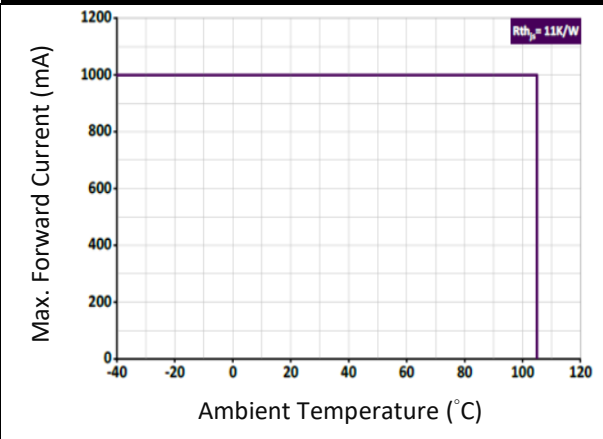
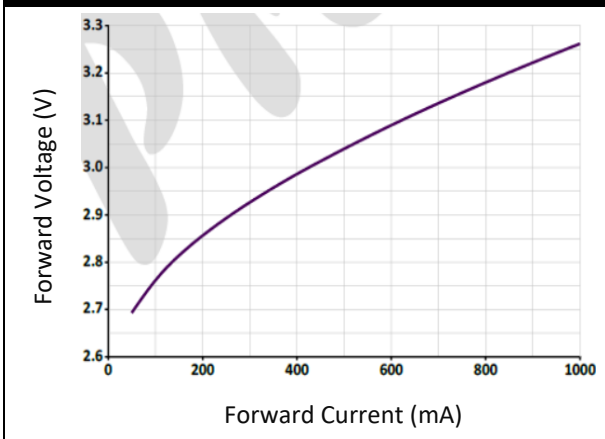
Code	Min.	Max.	Unit
PB2A	1200	1400	mW
PB4A	1400	1600	

 Peak Wavelength Classifications ($I_F=1A$; $t_p=10ms$):

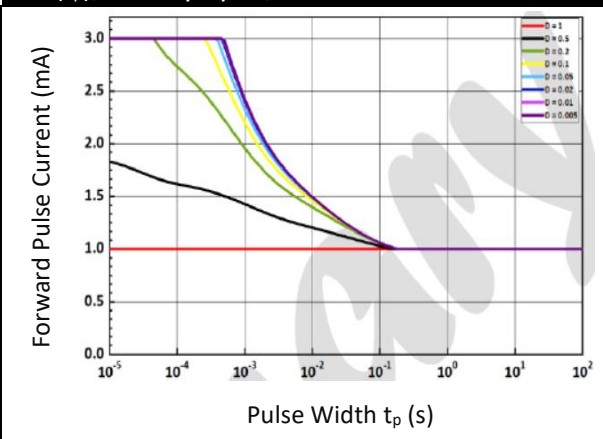
Code	Min.	Max.	Unit
F3	840	870	nm

ELECTRO-OPTICAL CHARACTERISTICS:
Radiant Power v.s. Forward Current

Radiant Intensity v.s. Forward Current

Relative Spectral Power v.s. Wavelength

Permissible Forward Current

$$I_{F(max)} = f(T_s); R_{thjs} = 11K/W$$

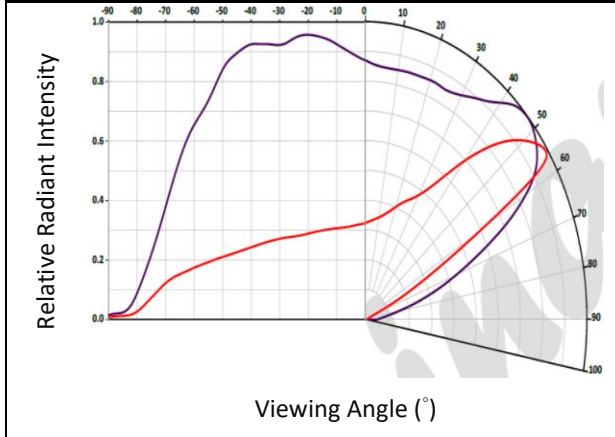

Forward Current v.s. Forward Voltage

Permissible Pulse Handling Capability

$$I_F = f(t_p); D = \text{Duty Cycle}; T_s = 85^\circ\text{C}$$



ELECTRO-OPTICAL CHARACTERISTICS:

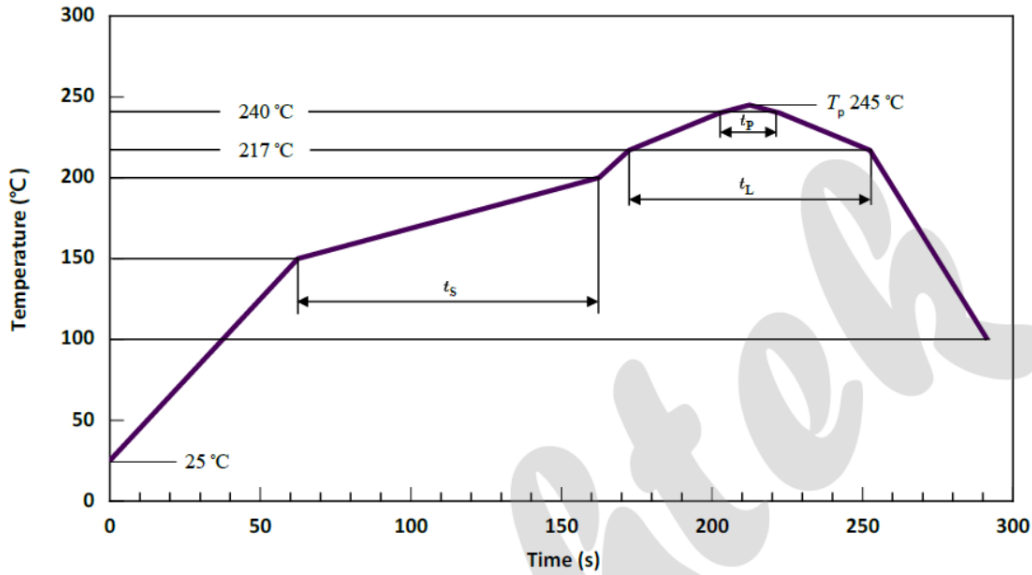
Directive Radiation (L=0)





RECOMMENDED SOLDERING PROFILE:

Reflow Lead-free Solder:



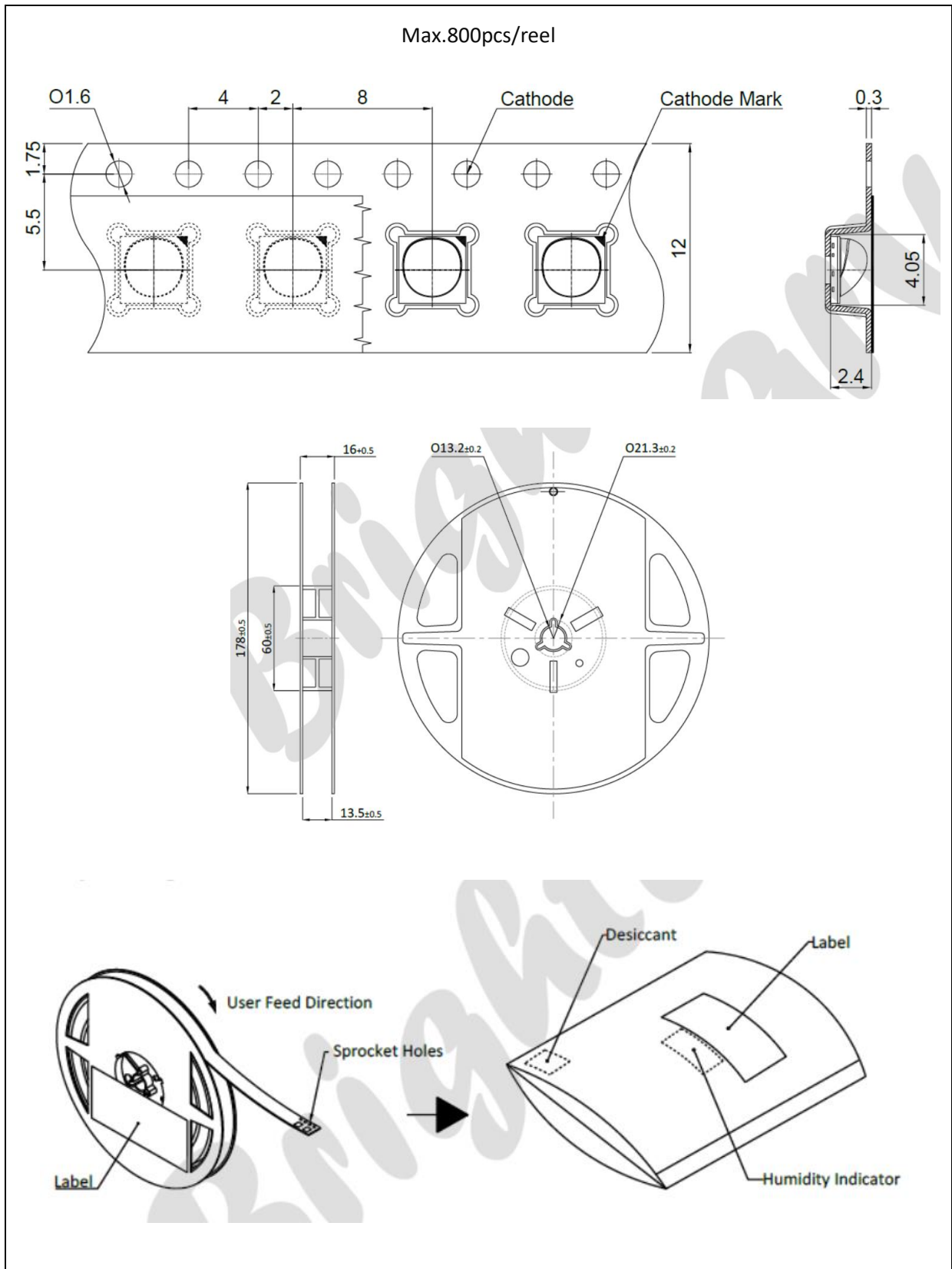
Profile Feature	Symbol	Pb-Free (SnAgCu) Assembly			Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat 25 °C to 150 °C			2	3	K/s
Time t_s T_{smin} to T_{smax}	t_s	60	100	120	s
Ramp-up rate to peak T_{smax} to T_p			2	3	K/s
Liquidus temperature	T_L		217		°C
Time above liquidus temperature	t_L		80	100	s
Peak temperature	T_p		245	260	°C
Time within 5 °C of the specified peak temperature $T_p - 5$ K	T_p	10	20	30	s
Ramp-down Rate T_p to 100 °C			3	4	K/s
Time 25 °C to T_p				480	s

Note:

1. Maximum reflow soldering: 2 times.
2. Recommended soldering temperature is 245°C. The maximum soldering temperature should be limited to 260°C.
3. Before, during, and after soldering, should not apply stress on the components and PCB board.

PACKING SPECIFICATION:

Reel Dimension:



PRECAUTIONS OF USE:

Storage:

It is recommended to store the products in the following conditions:

- Humidity: 60% R.H. Max.
- Temperature: 5°C~30°C (41°F ~86°F).

Shelf life in sealed bag: 12 months at 5°C~30°C and <60% R.H.

Once the package is opened, the products should be used within a week. Otherwise, they should be kept in a damp-proof box with desiccating agent <10% R.H. and apply baking before use.

Baking:

It is recommended to bake the LED before soldering if the pack has been unsealed for longer than 24hrs. The suggested baking conditions are as followings:

- 60±3°C x 24hrs and <5%RH, taped / reel package.

It's normal to see slight color fading of carrier (light yellow) after baking in process.

Testing Circuit:



Must apply resistor(s) for protection (over current proof).

Cleaning:

Use alcohol-based cleaning solvents such as isopropyl alcohol to clean the LED carrier / package. Avoid putting any stress force directly on to the LED lens.

ESD (Electrostatic Discharge):

Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handling the LED all time. All devices, equipment, machinery, work tables, and storage racks must be properly grounded.

In the events of manual working in process, make sure the devices are well protected from ESD at any time.

REVISION RECORD:

Version	Date	Summary of Revision
A1.0	04/09/2024	Datasheet set-up.